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PATENT APPLICATION
Docket No. 4591-347
Client No. IB12109-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application for: Sung-Ho Kim Conf. No. 1351
Serial No.: 10/682,128 Examiner: Fahmy, Wael M.
Filing Date: October 7, 2003 Art Unit: 2814
Title: NONVOLATILE MEMORY DEVICE HAVING ASYMMETRIC
SOURCE/DRAIN REGION AND FABRICATING METHOD THEREOF

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

This Information Disclosure Statement is submitted:

☒ under 37 CFR 1.97 (b); or
(Within three months of filing national application; or date of entry of International application; or before mailing date of first office action on the merits; whichever occurs last)

☒ Applicant(s) submit herewith Form PTO 1449- Information Disclosure Citation together with copies of patents, publications or other information of which applicant(s) are aware, which applicant(s) believe(s) may be material to the examination of this application and for which there may be a duty to disclose in accordance with 37 CFR 1.56.

It is requested that the information disclosed herein be made of record in this application.

Copy of Hosoon Lee's Limited Recognition form Under 37 CFR § 10.9(b).

Any deficiency or overpayment should be charged or credited to deposit account number 13-1703. A duplicate copy of this sheet is enclosed.

Customer No. 20575

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

Hosoon Lee
Limited Recognition Under 37 CFR § 10.9(b)

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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Mail Stop Amendment Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450
Date: September 16, 2004

Adrienne Chocholak



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INFORMATION DISCLOSURE CITATION
FORM PTO-1449 (Modified)

FOREIGN PATENT DOCUMENTS

Exam Init	Ref	Document Number	Publication Date	Country	Name
_____	_____	2001-0091532	10/23/2001	Korea	Kim and Ryu

OTHER DOCUMENTS

Exam Init	Ref	Author, Title, Date, Pertinent Pages, Etc.)
_____	_____	English language Abstract for Korean Patent Publication No. 2001-0091532

Examiner: _____

Date Considered: _____